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Analysis of Electronic Waveguide Bends in Graphene Subject to Dirac Point Fluctuations

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Modelling and Simulations

Objectives

- Constructing a numerical solver for electron optics phenomena in graphene
- Studying the transmission properties of electronic waveguide bends in graphene
- Examining the effect of Dirac point fluctuations

- Electron optics in graphene
- Dirac point fluctuations
- Numerical method and setup
- Results of the simulation of a waveguide bend

Graphene and the Dirac equation

- Linear instead of parabolic dispersion relation
- Charge carriers are described by a (2+1)D massless Dirac equation
- $i\hbar \frac{\partial}{\partial t} \Psi = v_{\rm F} \, \boldsymbol{\sigma} \cdot \boldsymbol{\hat{p}} \, \Psi + V(x, y) \Psi$
 - $-\Psi = \begin{pmatrix} u \\ v \end{pmatrix}$ two component wavefunction
 - $v_{\rm F}$ Fermi velocity
 - $\boldsymbol{\sigma} = (\sigma_x, \sigma_y)$ Pauli spin matrices
 - $\widehat{p} = (\hat{p}_x, \hat{p}_y)$ momentum operator
- Appearance of "relativistic" phenomena



Electron optics in graphene

- Charge carriers behave similarly as light in ordinary optics
- The kinetic energy (E-V) takes over the role of refractive index.
- Kinetic energy can be zero or negative
- Possible applications: Veselago lens, beam splitters, reflectors, transistors, waveguides...
 - High contrast leads to excellent confinement



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Dirac point fluctuations

- Type of disorder in graphene layers
- Local variations of the potential
- Neutral graphene corresponds to a system of electron/hole puddles
- Origin: strain, substrate inhomogeneities
- Complicates the desired confinement in waveguides

Model for Dirac point fluctuations

Additional onsite correlated potential

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$$\epsilon_i = \frac{\sum_j \widetilde{\epsilon_j} \exp\left(-r_{ij}^2/2\eta^2\right)}{\sqrt{\sum_j \exp\left(-r_{ij}^2/\eta^2\right)}}$$

- $\tilde{\epsilon_j}$ normal distributed with zero mean and W standard deviation
- r_{ij} distance between lattice points i and j
- η correlation length

$$\eta = 10 \text{ nm } W = 5 \text{ meV}$$

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Numerical method

- Fourth-order accurate time-domain solver for the (2+1)D Dirac equation
- Spatial discretization
 - Staggered grid [1]
 - Fourth-order central difference
- Novel timestepping scheme
 - Partitioned Runge-Kutta method instead of standard j + 1/2Runge-Kutta
 - Fourth-order accurate
 - Lower memory consumption owing to fully in-place update scheme
 - Conservation of mass and energy





Setup

- Absorbing boundaries
- Total Field Scattered Field approach for the source
- Smooth potential supporting a single mode





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- Ideal situation
 - Mode adaptation losses
 - Low losses, even for very small radii



- With Dirac point fluctuations (DPFs)
 - Higher transmission than ideal situation is possible



- With Dirac point fluctuations (DPFs)
 - Decreasing the correlation length η increases the deviation



- With Dirac point fluctuations (DPFs)
 - Increasing the standard deviation W increases the deviation



- With Dirac point fluctuations (DPFs)
 - Example with Transmission = 0.40



Conclusion

- Constructed numerical solver capable of simulating electron optics phenomena and applications in graphene
- Electronic waveguide bends can be obtained that exhibit excellent transmission properties
- Dirac point fluctuations must be considered when studying electron optics phenomena in graphene